# SN54BCT125A, SN74BCT125A QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

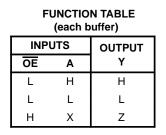
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- State-of-the-Art BiCMOS Design Significantly Reduces I<sub>CCZ</sub>
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Package Options Include Plastic Small-Outline (D) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (J, N)

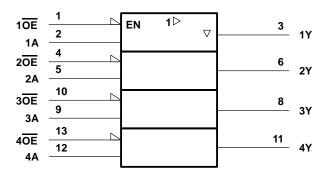
### description

The 'BCT125A bus buffer features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ( $\overline{OE}$ ) input is high.

The SN54BCT125A is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74BCT125A is characterized for operation from 0°C to 70°C.



## logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the J, N, and W packages.

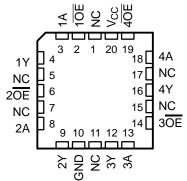
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN54BCT125A J OR W PACKAGE
SN74BCT125A D OR N PACKAGE
(TOP VIEW)

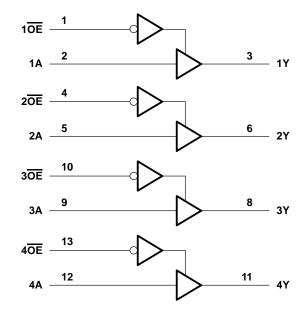
	•			
1 <u>0</u> E 1A 1Y	2	υ	12	V <sub>CC</sub>   40E   4A
2OE	4			] 4Y
2A[			10	3OE
2Y[	6		9	] 3A ] 3Y
GND	7		8	] 3Y

SN54BCT125A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

## logic diagram (positive logic)



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> Input voltage range, V <sub>I</sub> (see Note 1)		
Voltage range applied to any output in	the disabled or power-off state, VO	$\dots \dots \dots \dots - 0.5 \text{ V}$ to 5.5 V
Voltage range applied to any output in	the high state, VO	$\dots \dots \dots \dots - 0.5$ V to V <sub>CC</sub>
Current into any output in the low state	: SN54BCT125A	
	SN74BCT125A	128 mA
Operating free-air temperature range:	SN54BCT125A	– 55°C to 125°C
	SN74BCT125A	0°C to 70°C
Storage temperature range		– 65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### recommended operating conditions

		SN54BCT125A			SN74BCT125A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
Iк	Input clamp current			-18			-18	mA
ЮН	High-level output current			-12			-15	mA
IOL	Low-level output current			48			64	mA
Т <sub>А</sub>	Operating free-air temperature	-55		125	0		70	°C



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#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN	54BCT12	25A	SN	UNIT		
PARAMETER			MIN	түр†	MAX	MIN	түр†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	lj = –18 mA			-1.2			-1.2	V
		I <sub>OH</sub> = –3 mA	2.4	3.3		2.4	3.3		
VOH	V <sub>CC</sub> = 4.5 V	$I_{OH} = -12 \text{ mA}$	2	3.2					V
		I <sub>OH</sub> = -15 mA				2	3.1		
Voi	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA		0.38	0.55				V
VOL	$V_{OL}$ $V_{CC} = 4.5 V$	I <sub>OL</sub> = 64 mA					0.42	0.55	v
lj	$V_{CC} = 0,$	VI = 7 V			0.1			0.1	mA
IН	V <sub>CC</sub> = 5.5 V,	VI = 2.7 V			35			25	μΑ
۱ <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.5 V			-20			-20	μΑ
IOZH	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50			50	μΑ
IOZL	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0.5 V$			-50			-50	μA
los‡	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA
ICCH	V <sub>CC</sub> = 5.5 V,	Outputs open		19	31		19	31	mA
ICCL	V <sub>CC</sub> = 5.5 V,	Outputs open		46	49		46	49	mA
ICCZ	V <sub>CC</sub> = 5.5 V,	Outputs open		6	14		6	14	mA
Ci	V <sub>CC</sub> = 5 V,	V <sub>I</sub> = 2.5 V or 0.5 V		4			4		pF
Co	V <sub>CC</sub> = 5 V,	V <sub>O</sub> = 2.5 V or 0.5 V		9			9		pF

† All typical values are at V<sub>CC</sub> = 5 V.
‡ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

#### switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5 V,C_L = 50 pF,R1 = 500 Ω,R2 = 500 Ω,T_A = 25°C$			$V_{CC}$ = 4.5 V to 5.5 V, $C_L$ = 50 pF, R1 = 500 Ω, R2 = 500 Ω, $T_A$ = MIN to MAX <sup>§</sup>				UNIT
			MIN	CT125A	MAX	SN54BC MIN	MAX	SN74BC <sup>®</sup> MIN	MAX	
t <sub>PLH</sub>	A		1.6	3.5	5.2	1.6	6	1.6	5.7	
t <sub>PHL</sub>		А	Y	2.7	5	6.9	2.7	8	2.7	7.7
<sup>t</sup> PZH	ŌĒ	Y	3.4	6.7	9	3.4	11.1	3.4	10.3	
<sup>t</sup> PZL		Ť	5	8.2	10.4	5	12.8	5	11.7	ns
<sup>t</sup> PHZ	OE	Y	3	5.8	7.4	3	9.4	3	8.9	200
<sup>t</sup> PLZ			2.8	5.5	7.3	2.8	9.9	2.8	8.6	ns

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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